MITEL
SEMICONDUCTOR

SP8910 (MP)

5GHZ ÷10 Fixed Modulus Divider

Preliminary Information

DS4360 Issue 1.3 September 1999

The SP8910 is one of a range of very high speed low power prescalers for professional applications. The dividing elements are static D type flip flops and therefore allow operation down to DC if the drive signal is a pulse waveform with fast risetime. The output stage has internal100 ohm pull up resistors, giving a 0·5V p-p output. If required, an external 100 ohm can be connected in parallel to give a 50 ohm output.

Ordering Information

SP8910/KG/MP1S (tubes)
SP8910/KG/MP1T (tape and reel)

Features

- Very High Operating Speed
- Operation down to DC with Square Wave Input
- Silicon Technology for Low Phase Noise (Typically better than −140dBc/Hz at 1KHz)
- 5V Single Supply Operation
- Low Power Dissipation: 340mW (Typ.)
- Surface Mount Plastic Package

Absolute Maximum Ratings

Supply voltage, V_{CC}	6·5V
Storage temperature	−65°C to +150°C
Maximum junction temperature	+150°C
Prescaler input voltage	2·5Vp-p
Operating temperature	KG−40°C to +85°C T_{CASE}

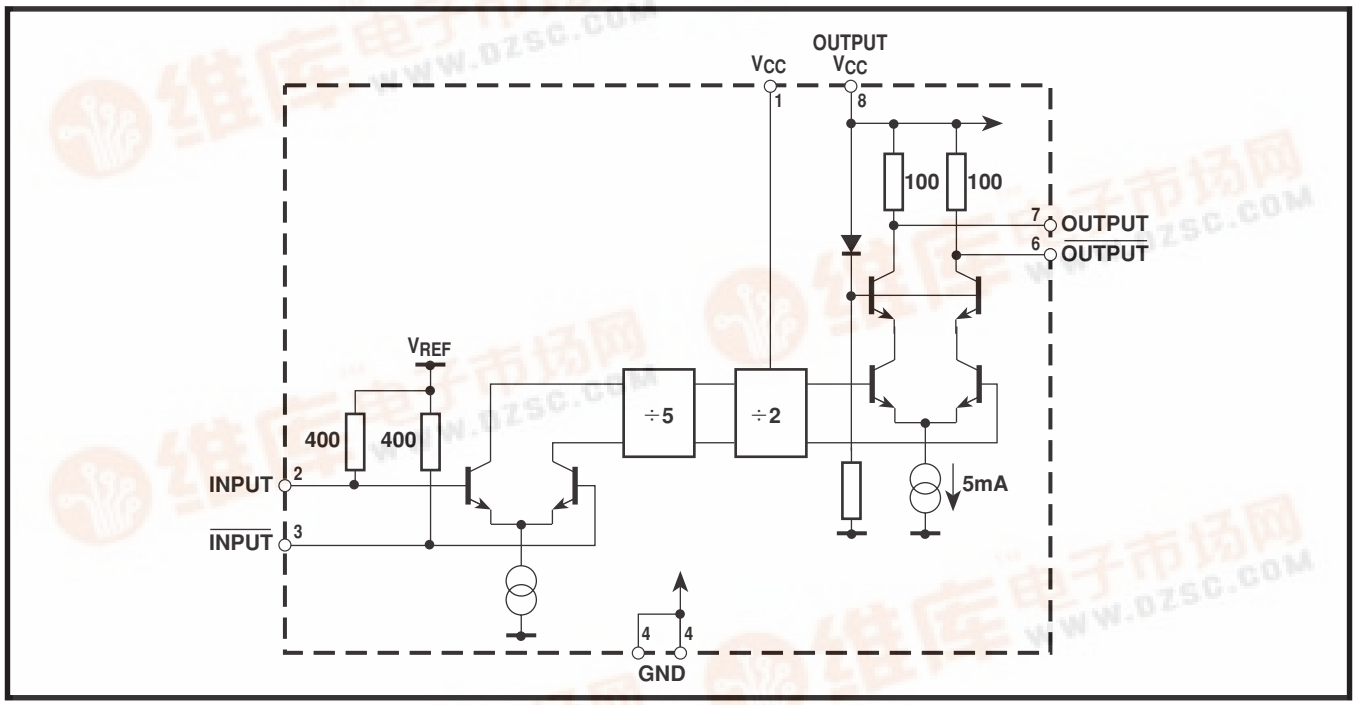


Figure 1 block diagram

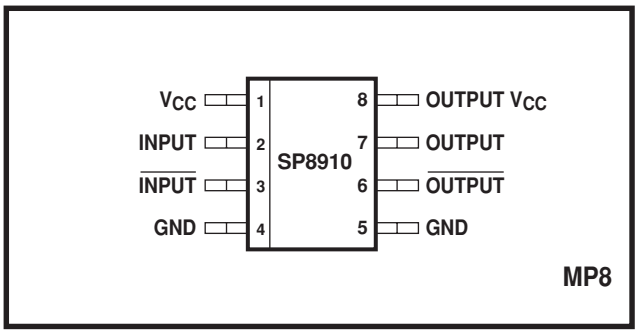


Figure 2 Pin connections - top view

Electrical Characteristics

These characteristics are guaranteed by either production test or design over the following range of operating conditions unless otherwise stated: T_{AMB} = −40°C to +85°C, V_{CC} = 4·75V to 5·25V

Characteristic	Pin	Value			Units	Conditions
		Min.	Typ.	Max.		
Supply current	1, 8	-	68	92	mA	
Input frequency	2, 3	1·0	-	5·0	GHz	RMS sinewave
Input frequency	2, 3	1·0		5·5	GHz	RMS sinewave, T_{CASE} = −55°C to +85°C
Input sensitivity	2, 3	-	-	180	mVrms	f_{IN} = 1GHz and 4.2GHz
Input sensitivity	2, 3	-	-	570	mVrms	f_{IN} = 5GHz
Input overload	2, 3	440	-	-	mVrms	f_{IN} = 1GHz and 3GHz
Input overload	2, 3	700	-	-	mVrms	f_{IN} = 5.0GHz and 3.8GHz
Output voltage	6, 7	-	0·25	-	Vp-p	Into 100Ω pullup resistor
Output power	6, 7	−18·0	−9·0	−4·0	dBm	f_{IN} = 1GHz and 5GHz (see note 1)

NOTE
1. Measured into 50Ω measuring instrument in parallel with 100Ω pullup resistor. See Figure 5.

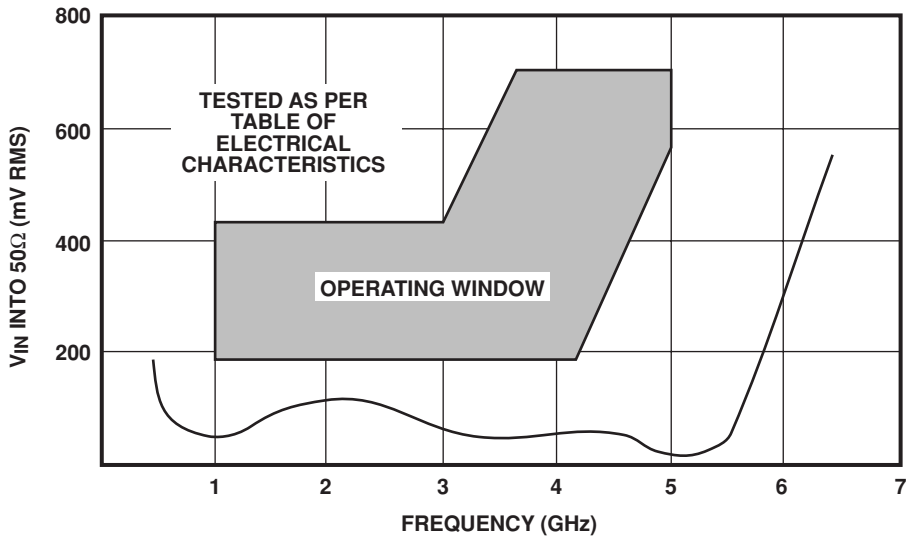


Figure3 Typical input sensitiviy (sinewave drive)

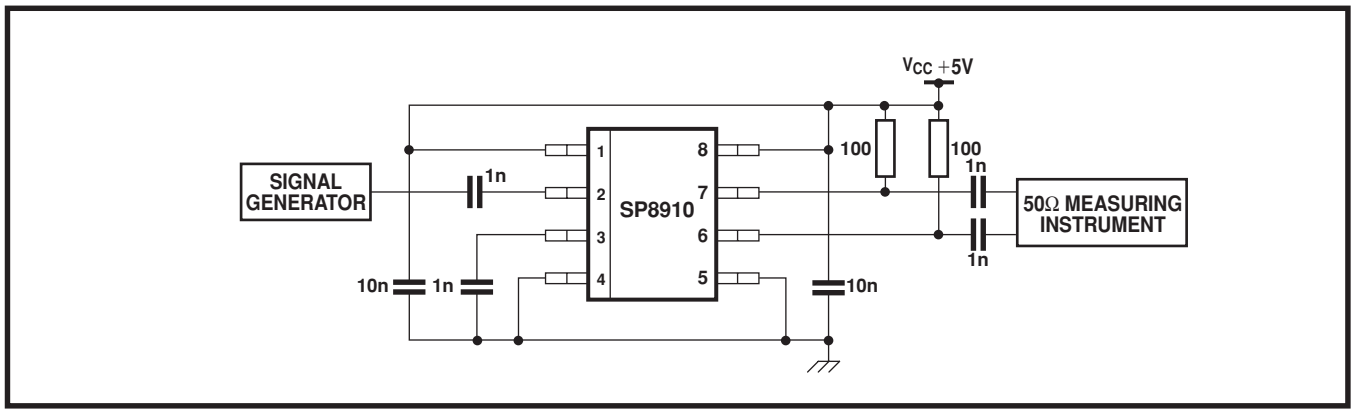


Figure 4 Typical application and test circuit

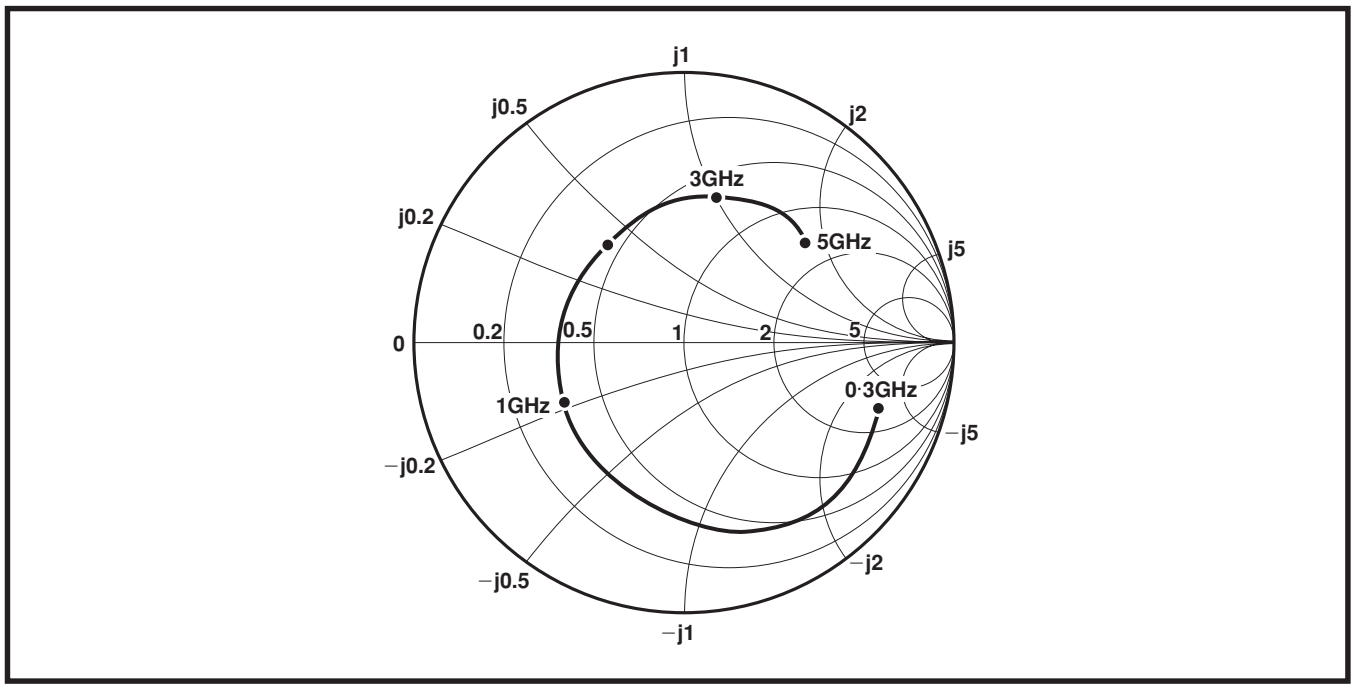


Figure 5 Typical input impedance

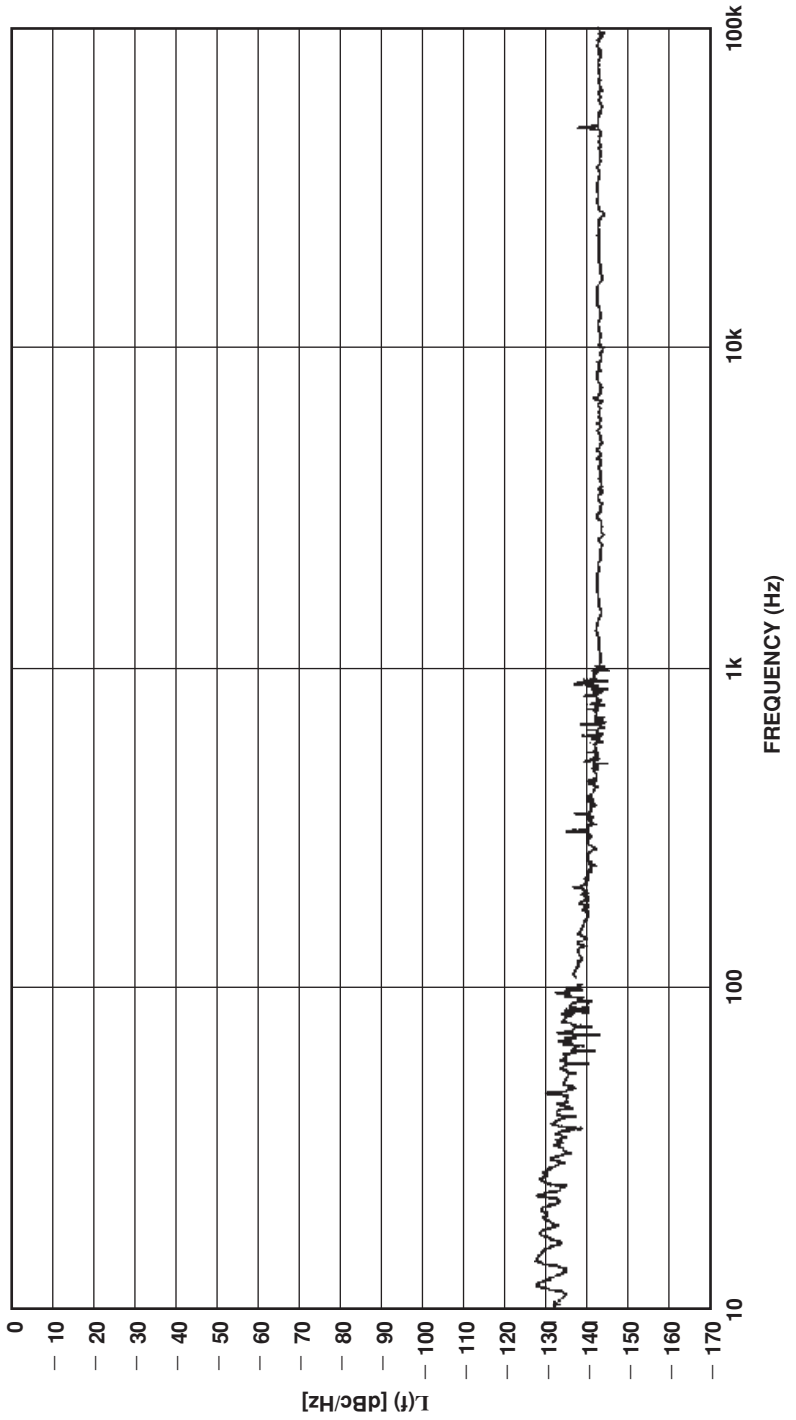
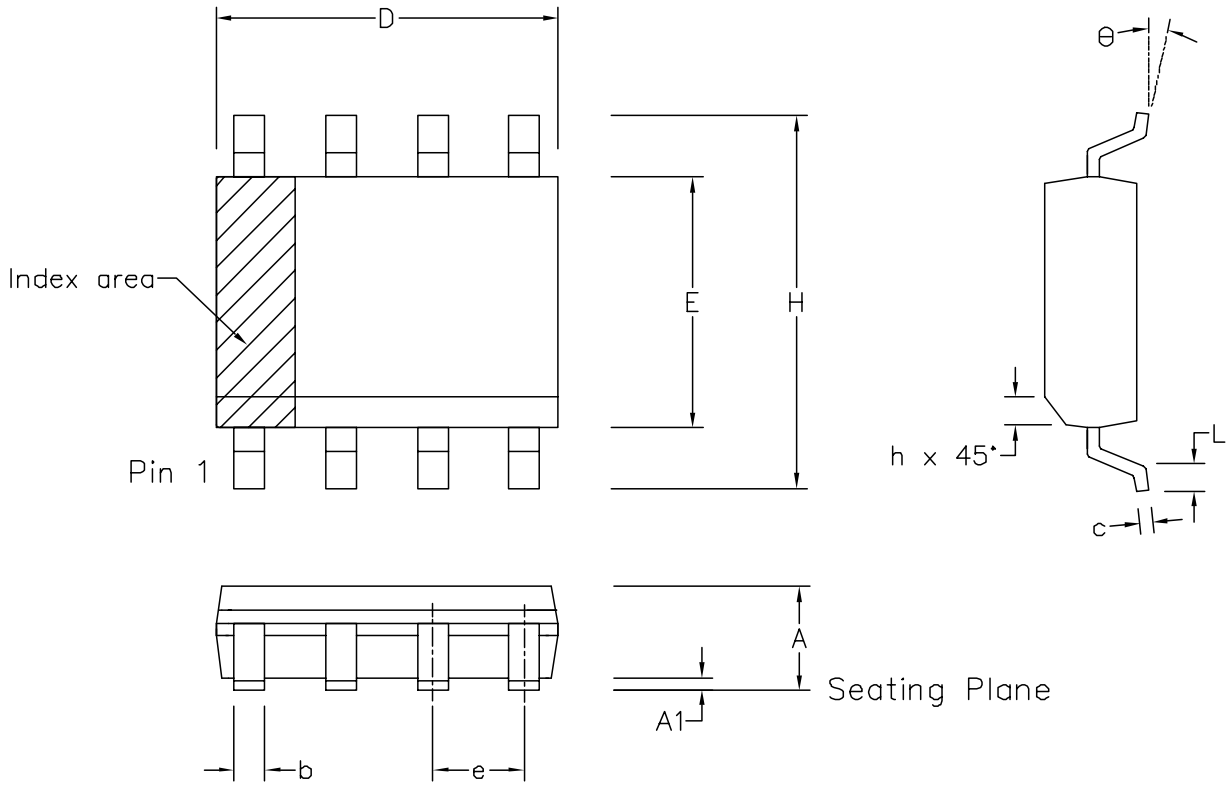


Figure 6 Typical phase noise, input frequency = 3GHz



	Min mm	Max mm	Min inch	Max inch
A	1.35	1.75	0.053	0.069
A1	0.10	0.25	0.004	0.010
D	4.80	5.00	0.189	0.197
H	5.80	6.20	0.228	0.244
E	3.80	4.00	0.150	0.157
L	0.40	1.27	0.016	0.050
e	1.27 BSC		0.050 BSC	
b	0.33	0.51	0.013	0.020
c	0.19	0.25	0.008	0.010
Θ	0°	8°	0°	8°
h	0.25	0.50	0.010	0.020
	Pin Features			
N	8		8	
Conforms to JEDEC MS-012AA Iss. C				

Notes:
1. The chamfer on the body is optional. If it not present, a visual index feature, e.g. a dot, must be located within the cross-hatched area.
2. Controlling dimension are in inches.
3. Dimension D do not include mould flash, protusion or gate burrs. These shall not exceed 0.006" per side.
4. Dimension E1 do not include inter-lead flash or protusion. These shall not exceed 0.010" per side.
5. Dimension b does not include dambar protusion/intrusion. Allowable dambar protusion shall be 0.004" total in excess of b dimension.

ORIGINATING SITE: SWINDON

ISSUE	1	2	3	4	
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APPROVED					

MITEL SEMICONDUCTOR

Title: Package Outline Drawing for 8 lds SOIC(N)-0.150" Body Width (M

Drawing Number
GPD00010

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